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#### Understanding <u>Embedded - CPLDs (Complex</u> <u>Programmable Logic Devices)</u>

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixedfunction ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

#### **Applications of Embedded - CPLDs**

#### Details

Product Status	Obsolete
Programmable Type	In System Programmable (min 10K program/erase cycles)
Delay Time tpd(1) Max	7 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	-
Number of Macrocells	128
Number of Gates	-
Number of I/O	80
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/atf1508re-7au100

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



## **Enhanced Features**

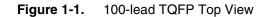
- Improved Connectivity (Additional Feedback Routing, Alternate Input Routing)
- Output Enable Product Terms
- Outputs Can Be Configured for High or Low Drive
- Combinatorial Output with Registered Feedback and Vice Versa within each Macrocell
- Three Global Clock Pins
- Fast Registered Input from Product Term
- Pull-up Option on TMS and TDI JTAG Pins
- OTF (On-the-Fly) Reconfiguration Mode
- DRA (Direct Reconfiguration Access)

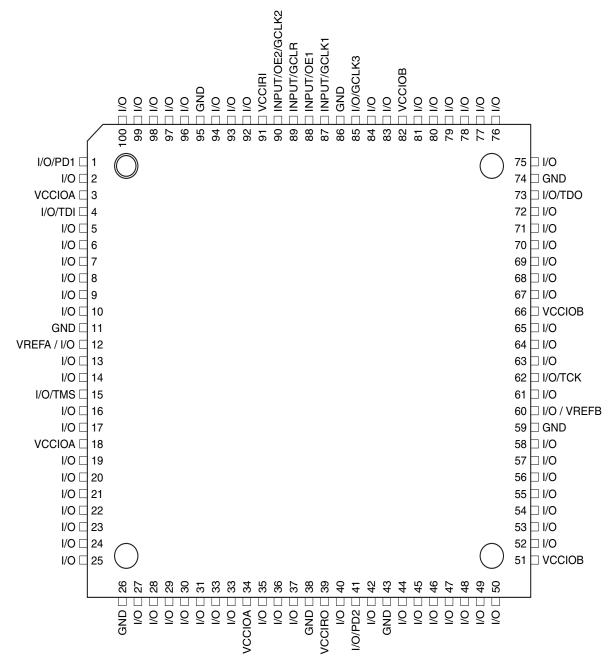
### 1. Description

The ATF1508RE is a high-performance, high-density complex programmable logic device (CPLD) that utilizes Atmel's proven electrically-erasable memory technology. With 128 logic macrocells and up to 84 inputs, it easily integrates logic from several TTL, SSI, MSI, LSI and classic PLDs. The ATF1508RE's enhanced routing switch matrices increase usable gate count and the odds of successful pin-locked design modifications.

The ATF1508RE has up to 80 bi-directional I/O pins, four dedicated input pins, 1 internal voltage regulator supply input pin (VCCIRI), 6 I/O VCC pins (VCCIOA and VCCIOB), 8 ground pins (GND and 1 internal voltage regulator output pin (VCCIR0). Each dedicated input pin can also serve as a global control signal, register clock, register reset or output enable. Each of these control signals can be selected for use individually within each macrocell. Figures 1-1 and 1-2 show the pin assignments for the 100-lead TQFP and 132-ball CBGA packages, respectively.

# 2 **ATF1508RE**





Note: VCCIRO (P39 for 100 TQFP) needs to be left floating and used for coupling (use 2.2 µF/or 4.7 µF X7R chip CAP and 470 pF NPO chip CAP.



#### Figure 1-2. 132-CBGA Top View

i iguit				10 10										
	1	2	3	4	5	6	7	8	9	10	11	12	13	14
А	() I/O	() VCCIRI	) I/GCLR	() 1/0	() I/0	() NC		⊖ NC	) GND	() 1/0	() I∕O	) I/0	() NC	
В	) I/O	() I/O	() GND	() 1/0	() I/0	() NC	() NC	$\bigcirc$ NC	 I/0/TDO	() NC	() I∕O	() I/O	() NC	
С	) I/O	() I/OE1	() I/OE2/ GCLK2	O VCCIOB	() I/0	() 1/0	() NC	$\bigcirc$ NC	() I/0	() 1/0	() I∕O	() I/O	() NC	
D	) I/O	() I/O	O NC									) I/O	() I/O	) 1/0
E	() I/O	() I/O	() I/0									) I/O	() 1/0	) GND
F	) I/O/PD1	() I/O	() I/0									) I/O	() 1/0	) 1/0
G	() I/O	() I/O	() I/0									) I/O/PD2	() 1/0	() VCCIOA
н	) I/O/VREFA	() I/O	() I/0									) I/O	() I/O	
J	() I/O	() 1/0										() I/O	() 1/0	
к	() I/O	()) GND	()  ∕0									O VCCIRI	() I/0	) 1/0
L	() NC	) I/GCLK1	() NC									) 1/0 1/	() /O/VREFI	С в 1/0
м	() NC	() NC	() I/0	() I/O	() I/O	() I/O	() NC	() 1/0	) I/O/TDI	() І/О/ТСК	() ⊮0	⊖ NC	() NC	
N	) GND	() NC	() I/0	) NC	() I/0	() 1/0	() NC	$\bigcirc$ NC		) I/O/TMS	() I/O	() GND	() I/0	) 1/0
Р	) VCCIRO	()  /0	()  /0		() I/0	() NC	() VCCIOA	⊖ NC	()  ∕0	() I/O	) 1/0	() I/O	() VCCIOA	() I/O

Notes: 1. The 132-ball CBGA package is 8 x 8 x 1.2 mm in size with 0.5 mm ball spacing.

 VCCIRO (P1 for 132 CBGA) needs to be left floating and connect to coupling CAP (use 2.2 μF/or 4.7 μF X7R chip CAP and 470PF or 1 nF NPO chip CAP.

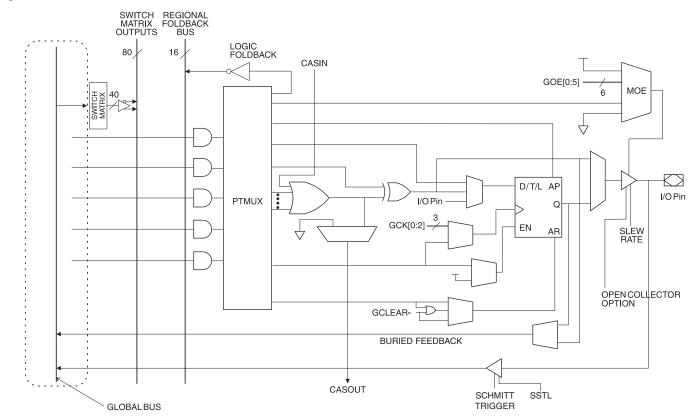


Each of the 128 macrocells generates a buried feedback signal that goes to the global bus (see Figure 1-3). Each input and I/O pin also feeds into the global bus. The switch matrix in each logic block then selects 40 individual signals from the global bus. Each macrocell also generates a foldback logic term that goes to a regional bus. Cascade logic between macrocells in the ATF1508RE allows fast, efficient generation of complex logic functions. The ATF1508RE contains eight such logic chains, each capable of creating sum term logic with a fan-in of up to 40 product terms.

The ATF1508RE macrocell, shown in Figure 1-4, is highly flexible and capable of supporting complex logic functions operating at high speed. The macrocell consists of five sections: product terms and product term select multiplexer, OR/XOR/CASCADE logic, a flip-flop, output select and enable, and logic array inputs.

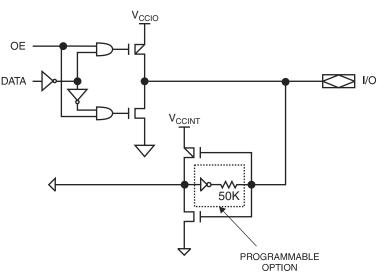
A security fuse, when programmed, protects the contents of the ATF1508RE. Two bytes (16 bits) of User Electronic Signature are accessible to the user for purposes such as storing project name, part number, revision or date. The User Electronic Signature is accessible regardless of the state of the security fuse.

The ATF1508RE device supports In-System Programming (ISP) via the industry-standard 4-pin JTAG interface (IEEE 1532 standard), and is fully compliant with IEEE 1149.1 for Boundary Scan Test. ISP allows the device to be programmed without removing it from the printed circuit board. In addition to simplifying the manufacturing flow, ISP also allows design modifications to be made in the field via software.



#### Figure 1-4. ATF1508RE Macrocell





#### 2.2 Schmitt Trigger

The Input Buffer of each input and I/O pin has an optional schmitt trigger setting. The schmitt trigger option can be used to buffer inputs with slow rise times.

#### 2.3 Output Drive Capability

Each output has a high/low drive option. The low drive option (slow slew rate) can be used to reduce system noise by slowing down outputs that do not need to operate at maximum speed or drive strength. Outputs default to high drive strength by Atmel software and can be set to low drive strength through the slew rate option.

#### 2.4 I/O Bank

The I/O pins of the ATF1508RE are grouped into two banks, Bank A and Bank B. Bank A comprises of I/O pins for macrocells 1 to 64 (Logic Block A, B, C, and D), and it is powered by  $V_{CCIOA}$ . Bank B comprises of I/O pins for macrocells 65 to 128 (Logic Block E, F, G, and H), and it is powered by  $V_{CCIOB}$ .

#### 2.5 I/O Standard

The ATF1508RE supports a wide range of I/O standards which include LVTTL, LVCMOS33, LVCMOS25, LVCMOS18 and LVCMOS15. The I/O pins of the ATF1508RE can also be individually configured to support SSTL-2 (Class I) and SSTL-3 (Class I) advanced I/O standards.

This and the two I/O banks, together, allow the ATF1508RE to be used for voltage level translation.



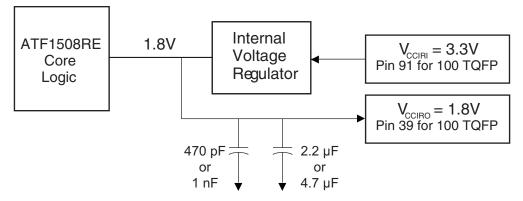


### 2.6 On-Chip Voltage Regulator

The ATF1508RE CPLD device has a built-in Internal Voltage Regulator that converts an external 3.3V supply to internal 1.8V core supply. The 1.8V output of the internal voltage regulator is also connected to the VCCIRO pin (Pin 39 for 100-pin TQFP) so that external bypass capacitors can be used to minimize noise. The recommended bypass capacitor values for the VCCIRO pin are 2.2  $\mu$ F or 4.7  $\mu$ F X7R, and 470 pF or 1 nF NPO type. These capacitors will help filter out noise at the output of the internal voltage regulator, which is important for the ATF1508RE to operate properly (see Figure 2-3).

The ATF1508RE CPLD also supports MultiVolt I/O interface feature, which allows seamless interface to other devices at 1.5V, 1.8V, 2.5V, or 3.3V logic levels. The ATF1508RE device has two I/O banks, each bank can be supplied with an independent VCCIO (VCCIOA or VCCIOB).





#### 3. Power Management

Unlike conventional CPLDs with sense amplifiers, the ATF1508RE is designed using low-power full CMOS design techniques. This enables the ATF1508RE to achieve extremely low power consumption over the full operating frequency spectrum.

The ATF1508RE also has an optional power-down mode. In this mode, current drops to below 100  $\mu$ A. When the power-down option is selected, either PD1 or PD2 pins (or both) can be used to power down the part. When enabled, the device goes into power-down when either PD1 or PD2 is high. In the power-down mode, all internal logic signals are latched and held, as are any enabled outputs.

All pin transitions are ignored until the PD pin is brought low. When the power-down feature is enabled, the PD1 or PD2 pin cannot be used as a logic input or output. However, the pin's macrocell may still be used to generate buried foldback and cascade logic signals.

All power-down AC characteristic parameters are computed from external input or I/O pins.

### 4. Security Feature

A fuse is provided to prevent unauthorized copying of the ATF1508RE fuse patterns. Once enabled, fuse reading or verification is inhibited. However, the 16-bit User Electronic Signature remains accessible. To reset this feature, the entire memory array in the device must be erased.

## 5. Programming Methods

The ATF1508RE devices are In-System Programmable (ISP) or In-System Configurable (ISC) devices utilizing the 4-pin JTAG protocol. This capability eliminates package handling normally required for programming and facilitates rapid design iterations and field changes.

When using the ISP hardware or software to program the ATF1508RE devices, four I/O pins must be reserved for the JTAG interface. However, the logic features that the macrocells have associated with these I/O pins are still available to the design for buried logic functions.

To facilitate ISP programming by the Automated Test Equipment (ATE) vendors, Serial Vector Format (SVF) files can be created by Atmel-provided software utilities. ATF1508RE devices can also be programmed using standard third-party programmers. With a third-party programmer, the JTAG ISP port can be disabled, thereby allowing four additional I/O pins to be used for logic.

The ATF1508RE device supports several configuration modes which gives designers several unique options for programming.

The different modes of programming are:

- ISC In-System Configuration
- OTF On-the-Fly Reconfiguration
- DRA Direct Reconfiguration Access

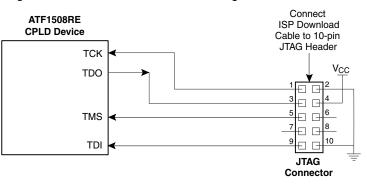
### 5.1 In-System Configuration – ISC (Also Referred to as ISP)

This mode is the de-facto standard used to program the CPLD when it is attached to a PCB. The term ISC can also be used interchangeably with ISP (In-system Programming). ISC or ISP eliminates the need for an external device programmer, and the devices can be soldered to a PCB without being preprogrammed.

In the ISC mode, the logic operation of the ATF1508RE is halted and the embedded configuration memory is programmed. The device is programmed by first erasing the configuration memory in the CPLD and then loading the new configuration data into the memory, which in-turn configures the PLD for functional mode. When the device is in the ISC programming mode, all user I/Os are held in the high impedance state.

The ISC mode is best suited for working with the ATF1508RE device in a design development or production environment. Configuration of the ATF1508RE device done via a Download Cable (see Figure 5-1 on page 11) is the default mode used to program the device in the ISC mode. In this mode, the PC is typically the controlling device that communicates with the CPLD.

#### Figure 5-1. Configuration of ATF1508RE Device Using a Download Cable





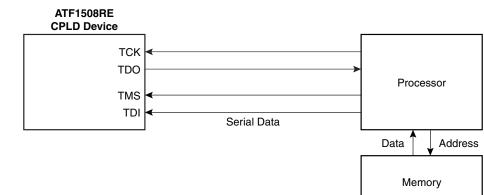


### 5.2 On-the-Fly Reconfiguration – OTF

In this mode, the CPLD design pattern stored in the internal configuration memory can be modified while the previously-programmed design pattern is operating with minimal disturbance to the programming operation of the new design. The new configuration will take affect after the OTF programming process is completed and the OTF mode is exited.

The configuration data for any design is stored in the internal configuration memory. Once the configuration data is transferred to the internal static registers of the CPLD, the CPLD operates with the design pattern and the configuration memory is free to be re-loaded with a new set of configuration data. The design pattern due to the new configuration content is activated through an initialization cycle that occurs on exiting the OTF mode or after the next power up sequence.

Figure 5-2 shows the electrical interface for configuration of the ATF1508RE device in the OTF mode. The processor is the controlling device that communicates with the CPLD and uses configuration data stored in the external memory to configure the CPLD.





#### 5.3 Direct Reconfiguration Access – DRA

This reconfiguration mode allows the user to directly modify the internal static registers of the CPLD without affecting the configuration data stored in the embedded memory. It is more useful in cases where immediate and temporary context change in the function of the hardware is desired.

The embedded configuration memory in the ATF1508RE does not change when a new set of configuration data is passed to the ATF1508RE using the DRA mode. Instead, the internal static registers of the CPLD are directly written with the data entering the device via the JTAG port. In other words, it's a temporary change in the function performed by the CPLD since a power sequence results in the device being configured again by the data stored in the embedded memory.

#### 5.4 ISP Programming Protection

The ATF1508RE has a special feature that locks the device and prevents the inputs and I/O from driving if the programming process is interrupted for any reason. The I/O pins default to high-Z state during such a condition.

All ATF1508RE devices are initially shipped in the erased state, thereby making them ready to use for ISP.

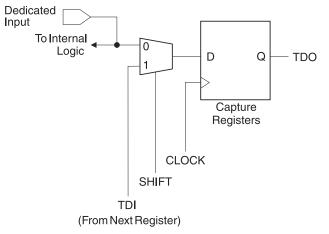
### 6. JTAG-BST/ISP Overview

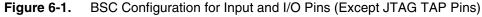
The JTAG boundary-scan testing is controlled by the Test Access Port (TAP) controller in the ATF1508RE. The boundary-scan technique involves the inclusion of a shift-register stage (contained in a boundary-scan cell) adjacent to each component so that signals at component boundaries can be controlled and observed using scan testing methods. Each input pin and I/O pin has its own boundary-scan cell (BSC) to support boundary-scan testing. The TAP controller is automatically reset at power-up. The five JTAG modes supported include: SAMPLE/PRE-LOAD, EXTEST, BYPASS, IDCODE and HIGHZ. The ATF1508RE's BSC can be fully described using a BSDL file as described in IEEE 1149.1 standard. This allows ATF1508RE testing to be described and implemented using any one of the third-party development tools supporting this standard.

The ATF1508RE also has the option of using the four JTAG-standard I/O pins for ISP. The ATF1508RE is programmable through the four JTAG pins using the IEEE standard JTAG programming protocol established by IEEE 1532 standard using 1.8V/2.5V/3.3V LVCMOS level programming signals from the ISP interface for in-system programming. The JTAG feature is a programmable option. If JTAG (BST or ISP) is not needed, then the four JTAG control pins are available as I/O pins.

### 6.1 JTAG Boundary-scan Cell (BSC) Testing

The ATF1508RE contains 80 I/O pins and four dedicated input pins. Each input pin and I/O pin has its own boundary-scan cell (BSC) in order to support boundary-scan testing as described in detail by IEEE 1532 standard. A typical BSC consists of three capture registers or scan registers and up to two update registers. There are two types of BSCs, one for input or I/O pin, and one for the macrocells. The BSCs in the device are chained together through the capture registers. Input to the capture register chain is fed in from the TDI pin while the output is directed to the TDO pin. Capture registers are used to capture active device data signals, to shift data in and out of the device and to load data into the update registers. Control signals are generated internally by the JTAG TAP controller. The BSC configuration for the input and I/O pins and macrocells is shown below.

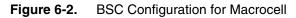


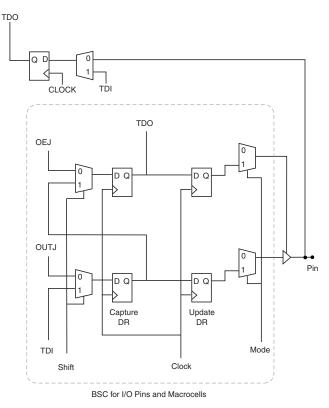


Note: The ATF1508RE has a pull-up option on TMS and TDI pins. This feature is selected as a design option.









## 7. Design Software Support

ATF1508RE designs are supported by several third-party tools. Automated fitters allow logic synthesis using a variety of high-level description languages such as VHDL<sup>®</sup> and Verilog<sup>®</sup>. Third party synthesis and simulation tools from Mentor Graphics<sup>®</sup> are integrated into Atmel's software tools.

# 8. Electrical Specifications

Table 8-1.	Absolute Maximum	Ratings*
		naungs

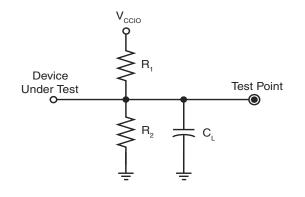
Operating Temperature40° C to +85° C
Storage Temperature65° C to +150° C
Supply Voltage (V <sub>CCINT</sub> )0.5V to +2.5V
Supply Voltage for Output Drivers (V <sub>CCIO</sub> )–0.5V to +4.5V
Junction Temperature55°C to +155°C

\*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Condition	Min	Тур	Max	Units
V <sub>CCIRI</sub>	Supply Voltage for internal logic and input buffers		3.0	3.3	3.6	V
V <sub>CCIO</sub>	Supply Voltage for output drivers at 3.3V		3.0	3.3	3.6	V
V <sub>CCIO</sub>	Supply Voltage for output drivers at 2.5V		2.3	2.5	2.7	V
V <sub>CCIO</sub>	Supply Voltage for output drivers at 1.8V		1.7	1.8	1.9	V
V <sub>CCIO</sub>	Supply Voltage for Output Drivers at 1.5V		1.4	1.5	1.6	v
I <sub>SB_IO</sub>	Standby Current, VCCIO	$V_{CCIO} = 3.3V$ , $V_{CCIRI} = 3.3V$		1		μA
I <sub>SB_INT</sub>	Standby Current, V <sub>CC</sub> Core <sup>(1)</sup>	$V_{CCIRI} = 3.3V, V_{CCIO} = 3.3V$		130		μA
I <sub>CC_INT(HD)</sub>	Operating Current <sup>(1)</sup> for V <sub>CCIRI</sub> (supply voltage)	$\label{eq:V_CCIRI} \begin{array}{l} V_{CCIRI} = 3.3V, \ V_{CCIO} = 3.3V, \\ f = 1 \ MHz \end{array}$		450		μA
I <sub>CC_IO(HD)</sub>	Operating Current <sup>(1)</sup> for $V_{CCIO}$ (supply voltage for output drivers), per LAB	$V_{CCIRI} = 3.3V$ , $V_{CCIO} = 3.3V$ , f = 1 MHz		375		μA
I <sub>CC_INT(LD)</sub>	Operating Current <sup>(1)</sup> for $V_{CCIRI}$ (low drive)	$V_{CCIRI} = 3.3V, V_{CCIO} = 3.3V, f = 1 MHz$		450		μA
I <sub>CC_IO(LD)</sub>	Operating Current <sup>(1)</sup> for $V_{CCIO}$ (supply voltage for output drivers), per LAB	$V_{CCIRI} = 3.3V, V_{CCIO} = 3.3V,$ f = 1 MHz		150		μA
I <sub>IL</sub> , I <sub>IH</sub>	Input Leakage	$V_{CCIRI} = 3.3V, V_{IN} = 0V \text{ or } 1.9V$			±1	μA
I <sub>OZH</sub> , I <sub>OH</sub>	Output or IO Leakage	$\label{eq:V_CCIRI} \begin{array}{l} V_{CCIRI} = 3.3V,  V_{CCIRO} = 3.6V, \\ V_{IN} = 0V \text{ or } V_{CCIRO} \end{array}$			±1	μA
LVCMOS 3.	3V & LVTTL (HD: High Drive, LD	: Low Drive)				
V <sub>IL</sub>	Input Low-voltage		-0.3		0.8	V
V <sub>IH</sub>	Input High-voltage		2		3.9	V
		HD: $I_{OL} = 8$ mA, $V_{CCIO} = 3V$			0.4	V
V <sub>OL</sub>	Output Low-voltage	LD: $I_{OL} = 1$ mA, $V_{CCIO} = 3V$			0.4	V
M	Output Lligh voltage	HD: $I_{OH} = -8 \text{ mA}, V_{CCIO} = 3V$	V <sub>CCIO</sub> - 0.4V			V
V <sub>OH</sub>	Output High-voltage	LD: $I_{OH} = -1 \text{ mA}, V_{CCIO} = 3V$	V <sub>CCIO</sub> - 0.4V			V
LVCMOS 2.	5V					
V <sub>IL</sub>	Input Low-voltage		-0.3		0.7	V
V <sub>IH</sub>	Input High-voltage		1.7		3.9	V
V	Output Low-voltage	HD: $I_{OL} = 8$ mA, $V_{CCIO} = 2.3V$			0.4	V
V <sub>OL</sub>	Oulput Low-voltage	LD: $I_{OL} = 1$ mA, $V_{CCIO} = 2.3V$			0.4	V
		HD: $I_{OH} = -8$ mA, $V_{CCIO} = 2.3V$	V <sub>CCIO</sub> - 0.4V			V
V <sub>OH</sub>	Output High-voltage	LD: I <sub>OH</sub> = -1 mA, V <sub>CCIO</sub> = 2.3V	V <sub>CCIO</sub> - 0.4V			V

AIMEL

# 10. Output AC Test Loads



	R1	R2	CL
LVTTL	350 Ohm	350 Ohm	35 pF
LVCMOS33	300 Ohm	300 Ohm	35 pF
LVCMOS25	200 Ohm	200 Ohm	35 pF
LVCMOS18	150 Ohm	150 Ohm	35 pF

Note:  $C_L$  includes test fixtures and probe capacitance.





# **11. AC Characteristics**

### Table 11-1. AC Characteristics <sup>(1)</sup>

			-{	5	-7		
Symbol	Parameter	=	Min	Max	Min	Max	Units
t <sub>PD1_INP</sub>	Delay for Single Input to Non-registered Outp	ut		5.0		6	ns
t <sub>PD1</sub>	Input or Feedback to Non-registered Output			7		7.5	ns
t <sub>PD2</sub>	Input or Feedback to Non-registered Feedbac	xk		4.2		4.7	ns
t <sub>su</sub>	Global Clock Setup Time		2.2		2.8		ns
t <sub>H</sub>	Global Clock Hold Time		0		0		ns
t <sub>FSU</sub>	Global Clock Setup Time of Fast Input		1		2		ns
t <sub>FH</sub>	Global Clock Hold Time of Fast Input		0.5		0.75		ns
t <sub>COP</sub>	Global Clock to Output Delay			6		6.9	ns
t <sub>CH</sub>	Global Clock High Time		1.25		2		ns
t <sub>CL</sub>	Global Clock Low Time		1.25		2		ns
t <sub>ASU</sub>	Array Clock Setup Time		1.7		2.2		ns
t <sub>AH</sub>	Array Clock Hold Time		0.50		0.60		ns
t <sub>ACOP</sub>	Array Clock to Output Delay			6.5		7.5	ns
t <sub>ACH</sub>	Array Clock High Time		1.75		2.5		ns
t <sub>ACL</sub>	Array Clock Low Time		1.75		2.5		ns
t <sub>CNT</sub>	Minimum Global Clock Period			3		4.75	ns
f <sub>CNT</sub>	Maximum Internal Global Clock Frequency		333		210		MHz
t <sub>ACNT</sub>	Minimum Array Clock Period			4		5.5	ns
f <sub>ACNT</sub>	Maximum Internal Array Clock Frequency		250		181		MHz
f <sub>MAX_EXT_SYNC</sub>	Maximum External Frequency V <sub>C</sub>	<sub>CCIO</sub> = 3.3V		122		103	MHz
f <sub>MAX_EXT_ASYNC</sub>	Maximum External Frequency V <sub>C</sub>	<sub>CCIO</sub> = 3.3V		122		103	MHz
t <sub>IN</sub>	Input Pad and Buffer Delay		0.7			0.9	ns
t <sub>IO</sub>	I/O Input Pad and Buffer Delay		0.7			0.9	ns
t <sub>FIN</sub>	Fast Input Delay			1		1	ns
t <sub>SEXP</sub>	Foldback Term Delay			2		3	ns
t <sub>PEXP</sub>	Cascade Logic Delay			0.5		1.0	ns
t <sub>LAD</sub>	Logic Array Delay			1.8		1.8	ns
t <sub>LAC</sub>	Logic Control Delay			1.5		2	ns
t <sub>IOE</sub>	Internal Output Enable Delay			2		2	ns
	Vc	<sub>CCIO</sub> = 1.5V		4.5		4.5	
t <sub>OD1</sub>		$c_{CIO} = 1.8V$		4.0		4.0	ns
		$c_{CIO} = 2.5V$		3.5 2.8		3.5 2.8	-
	V <sub>C</sub>	<sub>CCIO</sub> = 3.3V		2.0		∠.ō	



### 12. Power-down Mode

The ATF1508RE includes an optional pin-controlled power-down feature. When this mode is enabled, the PD pin acts as the power-down pin. When the PD pin is high, the device supply current is reduced to less than 100 µA. During power-down, all output data and internal logic states are latched and held. Therefore, all registered and combinatorial output data remain valid. Any outputs that were in a high-Z state at the onset will remain at high-Z. During power-down, all input signals except the power-down pin are blocked. Input and I/O hold latches remain active to ensure that pins do not float to indeterminate levels, further reducing system power. The power-down pin feature is enabled in the logic design file or through Atmel software. Designs using the power-down pin may not use the PD pin logic array input. However, all other PD pin macrocell resources may still be used, including the buried feedback and foldback product term array inputs.

		-5	-5/-7		
Symbol	Parameter	Min	Max	Units	
t <sub>IVDH</sub>	Valid I, I/O before PD High	10		ns	
t <sub>GVDH</sub>	Valid OE <sup>(2)</sup> before PD High	10		ns	
t <sub>CVDH</sub>	Valid Clock <sup>(2)</sup> before PD High	10		ns	
t <sub>DHIX</sub>	I, I/O Don't Care after PD High		5	ns	
t <sub>DHGX</sub>	OE <sup>(2)</sup> Don't Care after PD High		5	ns	
t <sub>DHCX</sub>	Clock <sup>(2)</sup> Don't Care after PD High		5	ns	
t <sub>DLIV</sub>	PD Low to Valid I, I/O		2	μs	
t <sub>DLGV</sub>	PD Low to Valid OE (Pin or Term)		2	μs	
t <sub>DLCV</sub>	PD Low to Valid Clock (Pin or Term)		2	μs	
t <sub>DLOV</sub>	PD Low to Valid Output		2	μs	

Table 12-1.	Power-down AC Characteristics <sup>(1)(2)</sup>
-------------	---

Notes: 1. For low-drive outputs, add t<sub>SSO</sub>.

2. Pin or product term.



Table 13-2. ATF1508RE I/O Pinouts

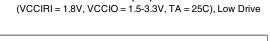
МС	Logic Block	100-lead TQFP	132-ball CBGA	МС	Logic Block	100-lead TQFP	132-ball CBGA
1	А	2	G1	33	С	25	B1
2	А	-	-	34	С	-	-
3	A/ PD1	1	F1	35	С	24	B2
4	А	-	-	36	С	-	-
5	А	100	F2	37	С	23	A1
6	А	99	F3	38	С	22	B4
7	А	-	-	39	С	-	-
8	А	98	E1	40	С	21	A4
9	А	97	E2	41	С	20	C5
10	А	-	-	42	С	-	-
11	А	96	E3	43	С	19	B5
12	А	-	-	44	С	-	-
13	А	94	D1	45	С	17	A5
14	А	93	D2	46	С	16	C6
15	А	-	-	47	С	-	-
16	А	92	C1	48	C/ TMS	15	N10
17	В	14	C2	49	D	37	P2
18	В	-	-	50	D	-	-
19	В	13	G3	51	D	36	М3
20	В	-	-	52	D	-	-
21	B/VREFA	12	H1	53	D	35	N3
22	В	10	H2	54	D	33	P3
23	В	-	-	55	D	-	-
24	В	9	H3	56	D	32	M4
25	В	8	J1	57	D	31	M5
26	В	-	-	58	D	-	-
27	В	7	J2	59	D	30	N5
28	В	-	-	60	D	-	-
29	В	6	K1	61	D	29	P5
30	В	5	K3	62	D	28	M6
31	В	-	-	63	D	-	-
32	B/ TDI	4	M9	64	D	27	N6

1.5V

<u>⊸</u> 1.8V

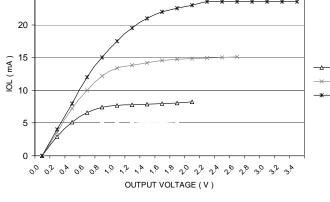
**→** 2.5V

—<del>\*</del>— 3.3∨

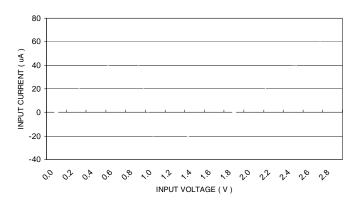


25

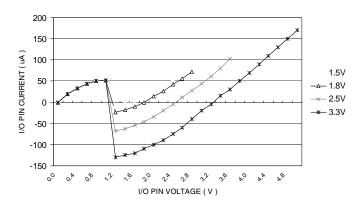
OUTPUT SINK CURRENT(IOL) VS. OUTPUT VOLTAGE



INPUT CURRENT VS. INPUT VOLTAGE INPUT PIN (VCCIRI = 3.3V, TA = 25C) (PIN-KEEPER ON)



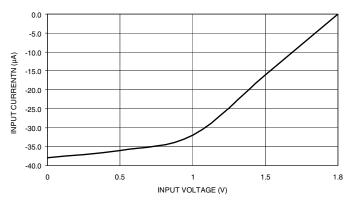
VO PIN CURRENT VS. VO PIN VOLTAGE I/O PIN (VCCIRI = 3.3V, VCCIO = 1.5V-3.3V, TA = 25C) (PIN KEEPER ON)



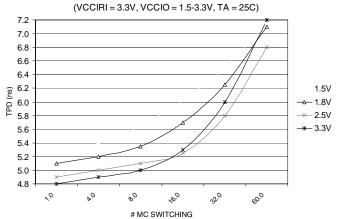
INPUT & I/O CURRENT VS. INPUT VOLTAGE VCCIRI = 3.3V, VCCIO = 1.8V (TA = 25°C) (Pull-Up On)

OUTPUT SOURCE CURRENT(IOH) VS. OUTPUT VOLTAGE

(VCCIRI = 1.8V, VCCIO = 1.5-3.3V, TA = 25C), Low Drive



TPD VS. # MC SWITCHING







# **15. Ordering Information**

# 15.1 Lead-free Package Options (RoHS Compliant)

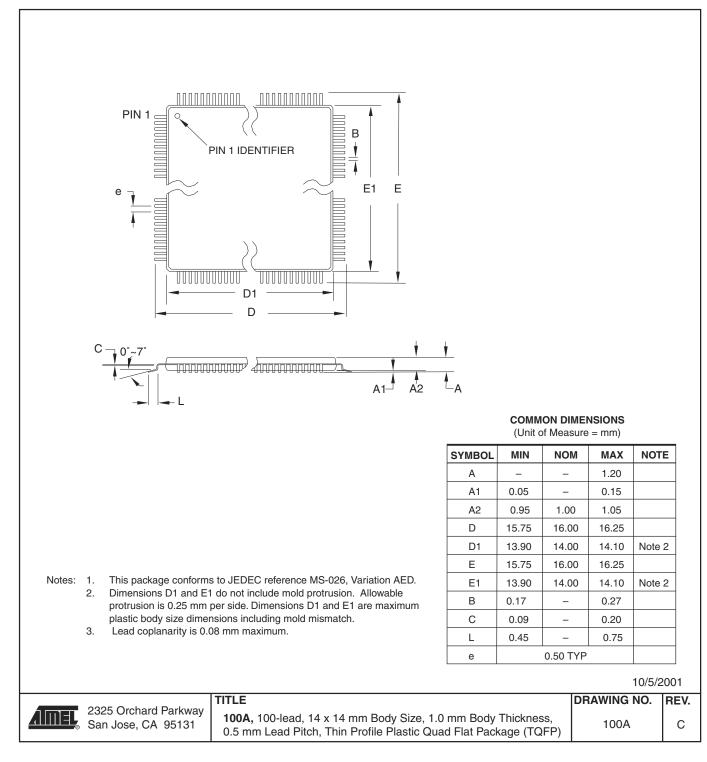
t <sub>PD</sub> (ns)	t <sub>co</sub> (ns)	Ordering Code	Package	Operation Range
5	6	ATF1508RE-5AX100	100A	Commercial (0° C to +70° C)
7	6.5	ATF1508RE-7AU100	100A	Industrial (-40° C to +85° C)
5	6	ATF1508RE-5CX132	132C1	Commercial (0° C to +70° C)
7	6.5	ATF1508RE-7CU132	132C1	Industrial (-40° C to +85° C)

Note: For shaded devices, contact marketing for availability.

Package Type				
100A	100-lead, Thin Plastic Gull Wing Quad Flatpack (TQFP)			
132C1	132-ball, Plastic Chip-Size Ball Grid Array Package (CBGA)			

# 16. Packaging Information









# 17. Revision History

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Revision Level – Release Date	History
A – October 2008	Initial release



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Literature Requests www.atmel.com/literature

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